Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L26	0	(chip and (transmission or transmitter) and (reception or receiver) and (overvoltage or electrostatic near2 discharge or voltage near2 surge or voltage near2 transient) and low near2 noise near2 amplifier).clm.	US-PGPUB	OR	ON	2005/11/21 11:49
L27	0	(chip and (transmission or transmitter) and (reception or receiver) and protection near2 unit and low near2 noise near2 amplifier), clm.	US-PGPUB	OR	ON	2005/11/21 11:49

Ref	Hits	Search Query	DBs	Default	Plurals	Time Stamp
#		10/554059	US-PGPUB;	Operator OR	ON	2005/11/21 10:14
L1	1	10/664968	USPAT	OK	011	2003/11/21 10.14
L2	1	("6400541").PN.	US-PGPUB; USPAT	OR	OFF	2005/11/21 10:14
L3	566	transceiver and esd	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/21 10:32
L4	465	3 and (integrated near12 circuit IC chip die)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/21 10:33
L5	463	3 and (integrated near2 circuit IC chip die)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/21 10:35
L6	417	5 and (low noise near2 amplifer LNA)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/21 10:58
L7	5933	transmitter near4 receiver same chip	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/21 10:58
L8	21	7 same (electrostatic overvoltage ESD)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/21 10:59
L9	21	7 same (electrostatic ESD)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/21 10:59
L10	76	((transceiver transmiter receiver) same semiconductor near2 chip ) and (overvoltage electrostatic esd)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/21 11:02
L11	3145	(361/56-58).CCLS.	US-PGPUB; USPAT	OR	OFF	2005/11/21 11:05
L12	0	("11sametransmitternear5receiver").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/21 11:03

L13	0	11 same transmitter near4 receiver	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/21 11:04
L14	46	11 and transmitter near4 receiver	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/21 11:05
L15	1967	(361/91.1,111).CCLS.	US-PGPUB; USPAT	OR	OFF	2005/11/21 11:05
L16	26	15 and transmitter near4 receiver	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/21 11:36
L17	2512	(361/117-120).CCLS.	US-PGPUB; USPAT	OR	OFF	2005/11/21 11:05
L18	46	17 and transmitter near4 receiver	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/21 11:05
L19	8	("5710984"   "5714900"   "5903820"   "5905623"   "5982165"   "6118984"   "6195535"   "6586993").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/11/21 11:24
L20	1	("6665159").PN.	US-PGPUB; USPAT	OR	OFF	2005/11/21 11:24
L21	5512	(transmission transmitter near4 reception receiver) same (electrostatic near2 breadown electrostatic near3 discharge ESD overvoltage voltage near2 transient voltage near2 spike voltage near2 surge)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/21 11:38
L22	261	21 same chip	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/21 11:42